

Two-impurity scattering in quasi-one-dimensional systems¹⁾

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Submitted 8 June 2021
Resubmitted 8 June 2021
Accepted 10 June 2021

DOI: 10.31857/S1234567821130097

In quasi-one-dimensional systems with low concentration of impurities the quantization of transverse electronic motion is essential and the conductivity demonstrates van Hove singularities when the Fermi level E_F approaches a bottom of some transverse quantization subband E_N . In our previous work [1, 2] we have demonstrated that for the case of a conducting tube of radius R with weak disorder potential present on its surface, the scattering at the central part of each singularity is suppressed by single impurity non-Born effects. However, single-impurity treatment of scattering breaks down at $|\varepsilon| \sim \varepsilon_{\min} = (n/\pi)^2$, where $\varepsilon = 2m^*R^2(E_F - E_N)$, m^* is effective electron mass, $n = n_2(2\pi R)^2$ is dimensionless concentration of point-like repulsing impurities. n and dimensionless scattering amplitude λ are assumed to be small: $n, \lambda \ll 1$. For simplicity, in the present paper we consider only the case of repulsing impurities $\lambda > 0$ and develop a theoretical description of multi-impurity effects in resistivity for $|\varepsilon| \lesssim \varepsilon_{\min}$. We show that these effects are effectively reduced to just two-impurity ones.

Scattering rate τ_{mk}^{-1} for state with longitudinal momentum k in an m -th subband of transversal quantization is related to corresponding self-energy $\Sigma_{mk}(\varepsilon)$: $\tau_{mk}^{-1} = -2\text{Im} \{\Sigma_{mk}\}$. The current-carrying states from (“nonresonant”) subbands with $m \neq N$ are semiclassical, therefore the self-energies are formally additive:

$$\Sigma_{mk} = \sum_i \Sigma_{mk}^{(i)}, \quad \Sigma_{mk}^{(i)} \equiv \Sigma^{(i)}(E = \varepsilon_m + k^2/2m^*).$$

Our aim is to account for all scattering processes within the resonant subband ($m = N$) exactly while for nonresonant subband ($m \neq N$) processes perturbative treat-

ment is sufficient. For perturbative scattering amplitude we have:

$$\begin{aligned} \tilde{V}_{m_1, m_2}^{(i)} &= V_{m_1, m_2}^{(i)} + V_{m_1, N}^{(i)} G_\varepsilon(z_i, z_i) V_{N, m_2}^{(i)} \equiv \\ &\equiv \frac{\tilde{\lambda}_i}{\pi^2} e^{i\phi_i(m_1 - m_2)}, \quad \tilde{\lambda}_i = \lambda \left\{ 1 + \frac{\lambda}{\pi^2} G_\varepsilon(z_i, z_i) \right\}. \end{aligned} \quad (1)$$

Here $G_\varepsilon(z_i, z_i)$ is the exact multi-impurity Green function of a strictly one-dimensional problem. In order to take into account multiple scattering, we solve the following Dyson equation:

$$\begin{aligned} \frac{\tilde{\Lambda}^{(i)(\text{ren})}}{\pi^2} &= \frac{\tilde{\lambda}^{(i)}}{\pi^2} + \frac{\tilde{\lambda}^{(i)}}{\pi^2} g_\varepsilon(0) \frac{\tilde{\Lambda}^{(i)(\text{ren})}}{\pi^2}, \\ g_\varepsilon(0) &= \sum_{m \neq N} g_\varepsilon^{(m)}(0) \approx -i\pi^2, \quad g_\varepsilon^{(m)}(0) = -\pi i \varepsilon_m^{-1/2}, \end{aligned} \quad (2)$$

where $g_\varepsilon^{(m)}(0)$ is the free one-dimensional Green function in the m -th subband. The solution of (2) reads:

$$\begin{aligned} \tilde{\Lambda}_i^{(\text{ren})} &= \lambda(q_i^{-1} + 1 + i\lambda)^{-1}, \quad (3) \\ q_i &= -[(\lambda/\pi^2)G_\varepsilon(z_i, z_i)]^{-1} - 1. \end{aligned} \quad (4)$$

In order to proceed we need to evaluate $G_\varepsilon(z_i, z_i)$. One-dimensional Green function satisfies the following Schroedinger equation:

$$\begin{aligned} \left\{ -\frac{1}{(2\pi)^2} \frac{d^2}{dz^2} + U(z) - \varepsilon \right\} G(z, z_i) &= -\delta(z - z_i), \quad (5) \\ U(z) &= \lambda/\pi^2 \sum_j \delta(z - z_j). \end{aligned} \quad (6)$$

However, for $|\varepsilon| \ll \varepsilon_{\text{nB}}$ one can show that it is enough to consider only 3 impurities:

$$U(z) \rightarrow \bar{U}(z) = \lambda/\pi^2 \sum_{j=i, i\pm 1} \delta(z - z_j). \quad (7)$$

Taking into account more distant impurities leads to only small corrections to $\text{Re} q_i$ and, at the same time,

¹⁾Supplementary materials are available for this article at DOI: ??? and are accessible for authorized users.

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to dramatic suppression of $\text{Im } q_i$. Therefore, for q_i we have: $q_i = q_i^{(+)} + q_i^{(-)}$, where

$$\begin{aligned} q_i^{(\pm)} &\approx (k/4\lambda) \cot k [L_i^{\pm} + 1/4\lambda], \quad k = 2\pi\sqrt{\varepsilon}, \\ L_i^{(+)} &= z_{i+1} - z_i, \quad L_i^{(-)} = z_i - z_{i-1}. \end{aligned} \quad (8)$$

Averaging over impurities positions, for resistivity $\rho(\varepsilon)$ we arrive at the following result:

$$\begin{aligned} \frac{\rho}{\rho_0} &= -\frac{1}{\lambda^2} \text{Im} \langle \Lambda^{(\text{ren})} \rangle_{L^{(\pm)}} = \\ &= \int_0^\infty \frac{\exp\{-n(L^{(+)} + L^{(-)})\} n^2 dL^{(+)} dL^{(-)}}{([q(L^{(+)}) + q(L^{(-)})]^{-1} + 1)^2 + \lambda^2}, \end{aligned} \quad (9)$$

where $\rho_0 = (4\pi/e^2 E_F) n(\lambda/\pi)^2$ is resistivity away from van Hove singularity. In principle, (9) together with (8) solve our problem: what is left is only to perform a double integration in (9) (see numerical results at Fig. 1). Below we do it analytically in different energy domains.

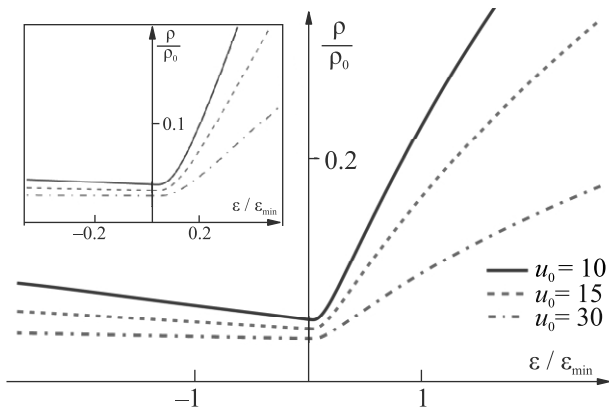


Fig. 1. (Color online) Plot of the total resistivity $\rho(\varepsilon)$ for $\lambda = 0.2$ (main plot) and $\lambda = 0.05$ (inset). In both cases three values of $u_0 = \lambda/n$ are used: $u_0 = 10, 15, 30$

For $\varepsilon > 0$ quasistationary states confined between pairs of adjacent impurities are present in the resonant subband, and for not very low ε the principal contribution to $\rho(\varepsilon)$ comes from resonant scattering at these states. The corresponding resonance condition is $kL = \pi p$, where $p = 1, 2, \dots$ and L is either $L_i^{(+)}$ or $L_i^{(-)}$. As a result, we obtain:

$$\frac{\rho_{\text{res}}}{\rho_0} = \frac{\pi n}{2\lambda^2} \sum_{p=1}^{\infty} e^{-nL_p} = \frac{\pi n}{2\lambda^2} \left[\exp\left(\frac{n}{2\sqrt{\varepsilon}}\right) - 1 \right]^{-1}. \quad (10)$$

However, $\rho_{\text{res}}(\varepsilon)$ vanishes at $\varepsilon \rightarrow 0$ and the finite contribution to $\rho(\varepsilon = 0)$ has non-resonant character. The most important nonresonant contribution ρ_{twin} comes

from anomalously small $L_i^{(+)}$ or $L_i^{(-)}$: $L^{(\pm)} \sim 1/\lambda \ll 1/n$. For ρ_{twin} we have:

$$\frac{\rho_{\text{twin}}}{\rho_0} \approx 2n \int_0^\infty \frac{e^{-nL} dL}{(4\lambda L + 2)^2} = \frac{n}{4\lambda}. \quad (11)$$

Why the scattering at twin impurities is dominant at low energy? There is no special enhancement for the twin impurities scattering at low ε , but single-impurity scattering amplitude $\Lambda_i^{(\text{ren})}$ is suppressed by non-Born effects for $\varepsilon \rightarrow 0$ [2]. This screening effect is, however, gradually destroyed, as a pair of impurities approach each other.

However, at the first glance this observation is counter-intuitive since the closer impurities are, the more their pair resembles a solitary “composite impurity”, scattering at which is expected to be suppressed. The resolution to this paradox is as follows. Let us consider transitions between states from $m, m' \neq N$ bands due to scattering at a twin pair. In this case, the scattering cross-section component that describes coherent scattering at 2 impurities constituting the pair is proportional to $e^{ik_{mm'}L}$, where $L = |z_i - z_j|$ and typical momentum transfer $k_{mm'}$ in a multi-channel system is large: $k_{mm'} \sim N \gg 1$. This contribution vanishes after averaging over L and, therefore, twin pair of impurities could be thought of as a “coherent” object for the processes within resonant subband but it is “incoherent” for scattering processes between states from current-carrying nonresonant subbands.

To conclude, we have studied the behavior of $\rho(\varepsilon)$ in a tube in the vicinity of a van Hove singularity. We have shown that in the range of energies $-(1/4)(\varepsilon_{\text{min}}\varepsilon_{\text{NB}})^{1/2} < \varepsilon < \varepsilon_{\text{min}} \ln^{-2} \lambda$ the resistivity is dominated by scattering at rare “twin” pairs of close defects. The predicted effect is characteristic for multi-channel systems, it can not be observed in strictly one-dimensional one.

This work was supported by Basic Research Program of The Higher School of Economics and by the Foundation for the Advancement of Theoretical Physics and Mathematics “Basis”.

The authors are indebted to I. S. Burmistrov and P. M. Ostrovsky for valuable comments.

Full text of the paper is published in JETP Letters journal. DOI: 10.1134/S0021364021130038

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